

View Online at <https://aerobasegroup.com/nsn/5961-00-014-6890>

Inclosure Material:

Metal

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage/static/base open all transistor and 50.0 collector to base voltage/static/emitter open all transistor

Current Rating Per Characteristic:

50.00 milliamperes zero-gate-voltage source current blank all transistor

Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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